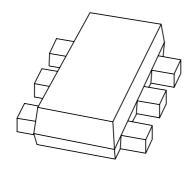
DISCRETE SEMICONDUCTORS

DATA SHEET



PEMB10 PNP resistor-equipped double transistor R1 = 2.2 kΩ, R2 = 47 kΩ

Preliminary specification

2001 Sep 14





PNP resistor-equipped double transistor R1 = 2.2 k Ω , R2 = 47 k Ω

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FEATURES

- 300 mW total power dissipation
- Very small 1.6 mm \times 1.2 mm \times 0.55 mm ultra thin package
- · Excellent coplanarity due to straight leads
- Reduces number of components as replacement of two SC-75/SC-89 packaged transistors
- Reduces required board space
- · Reduces pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

DESCRIPTION

PNP resistor-equipped double transistor in a SOT666 plastic package.

MARKING

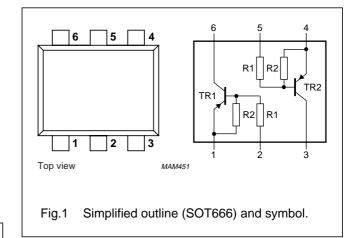
TYPE NUMBER	MARKING CODE
PEMB10	Z 5

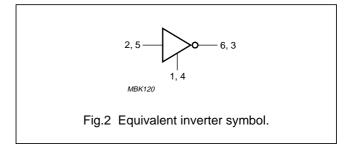
PINNING

PIN	DESCRIPTION				
1, 4	emitter	TR1; TR2			
2, 5	base	TR1; TR2			
6, 3	collector	TR1; TR2			

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-50	٧
I _{CM}	peak collector current	-100	mA
TR1	PNP	_	_
TR2	PNP	_	_
R1	bias resistor	2.2	kΩ
R2	bias resistor	47	kΩ





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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per transistor							
V _{CBO}	collector-base voltage	open emitter	_	-50	V		
V _{CEO}	collector-emitter voltage	open base	_	-50	V		
V_{EBO}	emitter-base voltage	open collector	_	-10	V		
VI	input voltage						
	positive		_	+12	V		
	negative		_	- 5	V		
Io	output current (DC)		_	-100	mA		
I _{CM}	peak collector current		_	-100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW		
T _{stg}	storage temperature		-65	+150	°C		
T _j	junction temperature		_	150	°C		
T _{amb}	operating ambient temperature		-65	+150	°C		
Per device	· · · · · · · · · · · · · · · · · · ·						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW		

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering method is reflow soldering.

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^{1.} Transistor mounted on an FR4 printed-circuit board.

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CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transistor						
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = -50 V	_	_	-100	nA
I _{CEO}	collector cut-off current	I _B = 0; V _{CE} = -50 V	_	_	-1	μΑ
		$I_B = 0$; $V_{CE} = -30 \text{ V}$; $T_j = 150 ^{\circ}\text{C}$	_	_	-50	μΑ
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = -5 V	_	_	-180	μΑ
h _{FE}	DC current gain	$I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}$	100	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	_	_	-100	mV
V _{i(off)}	input-off voltage	$I_C = -100 \mu\text{A}; V_{CE} = -5 \text{V}$	_	-0.6	-0.5	V
V _{i(on)}	input-on voltage	$I_C = -5 \text{ mA}; V_{CE} = -0.3 \text{ V}$	-1.1	-0.75	_	V
R1	input resistor		1.54	2.2	2.86	kΩ
R2 R1	resistor ratio		17	21	26	
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	_	_	3	pF

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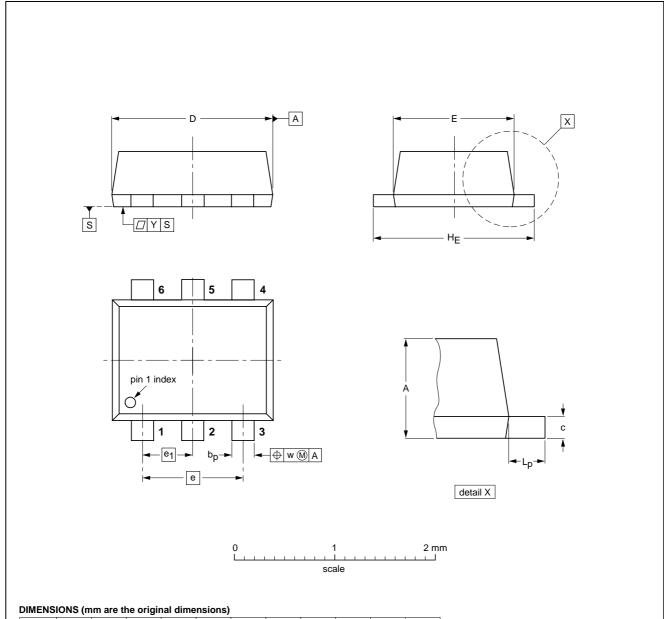
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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



UNIT	A	bp	С	D	E	е	e ₁	HE	L _p	w	у
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION			EIAJ		PROJECTION	ISSUE DATE	
SOT666						-01-01-04 01-08-27	

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Philips Semiconductors Preliminary specification

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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NOTES

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